TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SG126FU

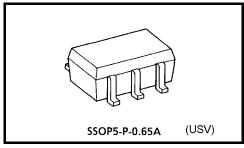
Bus Buffer with 3-STATE Output

Features

- High-level output current: I_{OH}/I_{OL} = ±8 mA (min)
- High-speed operation: t_{pd} = 2.4 ns (typ.)

at V_{CC} = 3.3 V,15pF

- Operating voltage range: V_{CC} = 0.9~3.6 V
- 5.5-V tolerant inputs.
- 3.6-V power down protection output.

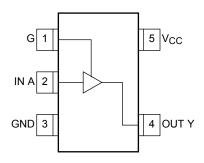


Weight: 0.006 g (typ.)

Marking

W C^k

Pin Assignment (top view)



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Vout	-0.5~ 4.6 (Note 1)	v
Input diode current	VOUT	-0.5~ V _{CC} + 0.5 (Note 2)	v
Output diode current	Iк	-20	mA
DC output current	I _{OK}	-20 (Note 3)	mA
DC V _{CC} /ground current	IOUT	±25	mA
Power dissipation	ICC	±50	mA
Storage temperature	PD	200	mW
Power supply voltage	T _{stg}	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

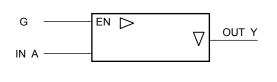
Note 1:
$$V_{CC} = 0V$$

Note 2: High or Low State. IOUT abusolute maximum rating must be observed.

Note 3: VOUT < GND

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IEC Logic Symbol



G	А	Y
L	Х	Z
Н	L	L
Н	Н	Н

Truth Table

Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	Vour	0~3.6 (Note 4)	V	
	Vout	0~V _{CC} (Note 5)	v	
		±8.0 (Note 6)		
	I _{OH} /I _{OL}	±4.0 (Note 7)		
Output Current		±3.0 (Note 8)	mA	
Output Current		UHUUL	±1.7 (Note 9)	ША
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4: $V_{CC} = 0V$

Note 5: High or Low state.

Note 6: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 7: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 8: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 9: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 10: V_{CC} = 1.1~1.3 V

Note 11: $V_{CC} = 0.9 V$

Note 12: $V_{IN} = 0.8 \sim 2.0 \text{ V}, \text{ V}_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition			٦	Га = 25°С)	Ta = -4	0~85°C	Unit				
Characteris	Sucs	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit				
					0.9	V _{CC}	_	_	V _{CC}	_					
					1.1~1.3	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_					
	High level	VIH		_	1.4~1.6	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_					
					1.65~ 1.95	V _{CC} × 0.65			V _{CC} × 0.65	_					
					2.3~2.7	1.7	_	_	1.7	_					
Input voltage					3.0~3.6	2.0	_	_	2.0	_	V				
input voltage					0.9	_		GND	_	GND	v				
					1.1~1.3	_		$V_{CC} \times 0.3$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$					
	Low level	VIL			1.4~1.6	_		$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$					
				-		_		$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$					
					2.3~2.7	—		0.7	—	0.7					
					3.0~3.6			0.8		0.8					
				evel V _{OH}		I _{OH} =-0.02 mA	0.9	0.75			0.75				
		High level V _{OH}	Vон		V _{OH}	V _{OH}		I _{OH} = -0.3 mA	1.1~1.3	V _{CC} × 0.75	_		V _{CC} × 0.75		-
	High level V _{OH}						V _{IN} = VIH	I _{OH} = -1.7 mA	1.4~1.6	V _{CC} × 0.75			V _{CC} × 0.75	_	
							-	VIH	I _{OH} = -3.0 mA	1.65~ 1.95	V _{CC} -0.45			V _{CC} -0.45	_
				I _{OH} = -4.0 mA	2.3~2.7	2.0	_	_	2.0 —						
Output voltage				I _{OH} = -8.0 mA	3.0~3.6	2.48			2.48		V				
Output voltage				I _{OL} = 0.02 mA	0.9	_		0.1	_	0.1	v				
				I _{OL} = 0.3 mA	1.1~1.3	_		V _{CC} × 0.25	_	V _{CC} × 0.25					
	Low level	V _{OL}	V _{IN} = VIL	I _{OL} = 1.7 mA	1.4~1.6			$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$		$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$					
			or VIH	I _{OL} = 3.0 mA	1.65~ 1.95	_		0.45	_	0.45					
				I _{OL} = 4.0 mA	2.3~2.7	—		0.4	—	0.4					
			I _{OL} = 8.0 mA		3.0~3.6	—		0.4	—	0.4					
Input leakage curre	ent	I _{IN}	V _{IN} = 0~5	5.5V	0~3.6		_	±0.1		±1.0	μA				
3-state output off-s	tate current	I _{OZ}	V _{IN} = V _{IH} V _{OUT} = 0	l or V _{IL} ~3.6V	0.9~3.6	_		1.0	_	10.0	μA				
Power off leakage	current	I _{OFF}	V _{IN} = 5.5 or V _{OUT} :	V = 3.6V	0.0	_		1.0	_	10.0	μΑ				
Quiescent supply of	current	ICC	$V_{IN} = V_{CO}$	_C or GND	3.6	_	_	1.0	_	10.0	μA				

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		-	Ta = 25°C)	Ta = -4	0~85°C	l la it
Characteristics			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
			0.9		15.3				
			1.1~1.3		8.3	18.4	1.0	34.2	
		C _L = 10 pF,	1.4~1.6		5.0	8.5	1.0	10.0	
		$R_{L} = 1 M\Omega$	1.65~ 1.95		4.0	6.2	1.0	6.7	
			2.3~2.7		2.6	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
			0.9	_	17.7				
			1.1~1.3	_	9.6	21.5	1.0	37.2	
Propagation delay time	t _{pLH}	C _L = 15 pF,	1.4~1.6	_	5.6	9.3	1.0	11.2	ns
Propagation delay time	t _{pHL}	$R_L = 1 M\Omega$	1.65~ 1.95		4.5	6.9	1.0	7.1	115
			2.3~2.7	_	2.9	4.4	1.0	5.0	
			3.0~3.6	_	2.4	3.4	1.0	3.9	
			0.9	_	29.0	_		_	
			1.1~1.3		14.5	29.6	1.0	56.0	
		$\begin{array}{l} C_L = 30 \text{ pF}, \\ R_L = 1 \text{ M}\Omega \end{array}$	1.4~1.6	_	8.2	13.1	1.0	15.9	
			1.65~ 1.95	_	6.0	9.2	1.0	9.6	
			2.3~2.7	_	4.0	5.7	1.0	6.1	
			3.0~3.6		3.3	4.4	1.0	4.8	
		$\begin{array}{l} C_L = 10 \text{ pF}, \\ R_L = 100 \text{ k}\Omega \end{array}$	0.9		22.7	_	_	_	
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.1~1.3	_	10.9	18.7	1.0	29.8	
			1.4~1.6		5.9	8.7	1.0	9.8	-
			1.65~ 1.95	_	4.5	6.3	1.0	6.8	
			2.3~2.7	_	3.1	4.2	1.0	4.5	
			3.0~3.6	_	2.4	3.2	1.0	3.5	
		$\begin{array}{l} C_L = 15 \text{ pF}, \\ R_L = 100 \text{ k}\Omega \end{array}$	0.9		25.3	_	_	_	
			1.1~1.3	_	11.9	20.7	1.0	34.7	
Output enable time	^t pZL		1.4~1.6		6.5	9.5	1.0	11.1	ns
	^t pZH	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		4.9	6.8	1.0	7.2	
		-	2.3~2.7		3.3	4.4	1.0	4.8	
			3.0~3.6		2.5	3.4	1.0	3.7	
		$\begin{array}{l} C_L = 30 \text{ pF}, \\ R_L = 100 \text{ k}\Omega \end{array}$	0.9		37.7			_	
			1.1~1.3		17.1	30.7	1.0	50.5	
			1.4~1.6	_	8.8	13.1	1.0	15.1	
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	6.6	9.2	1.0	9.9	
			2.3~2.7	_	4.1	5.4	1.0	5.8	
			3.0~3.6	_	3.1	4.1	1.0	4.5	

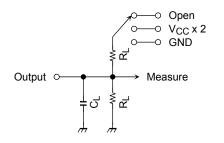
Characteristics	Symbol	Test Condition		٦	Га = 25°0)	Ta = -4	0~85°C	Unit		
Characteristics	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit		
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9		117.6		_	_			
			1.1~1.3	_	9.2	16.0	1.0	22.4			
			1.4~1.6	_	7.1	9.1	1.0	10.4			
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	6.7	8.3	1.0	9.0			
		-	2.3~2.7	_	6.2	7.3	1.0	8.8			
			3.0~3.6	_	5.8	6.9	1.0	7.6			
	^t pLZ tpHZ	$\begin{array}{l} C_L = 15 \text{ pF}, \\ R_L = 100 \text{ k}\Omega \end{array}$	0.9	_	139.2	_	_	_			
Output disable time			1.1~1.3	_	10.0	16.9	1.0	25.1			
			1.4~1.6	_	7.8	9.8	1.0	11.3	ns		
			$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	C _L = 15 pF, Rι = 5 kΩ	1.65~ 1.95	_	7.4	9.2	1.0	10.6	
				2.3~2.7	_	7.0	8.2	1.0	10.3		
			3.0~3.6	_	6.8	7.7	1.0	9.5			
		$\begin{array}{l} C_L=30 \text{ pF},\\ R_L=100 \text{ k}\Omega \end{array}$	0.9	_	230.8		_	_			
			1.1~1.3	_	14.0	20.8	1.0	31.9			
			1.4~1.6	_	12.2	13.5	1.0	14.9			
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	11.5	13.0	1.0	13.9			
		-	2.3~2.7	_	11.3	12.2	1.0	13.5			
			3.0~3.6	_	10.9	11.8	1.0	12.9			
Input capacitance	C _{IN}	_	3.6	_	3		_		pF		
Power dissipation capacitance	C _{PD}	(note13)	0.9 ~ 3.6		8	_	_		pF		

Note 13:C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

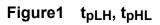
Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

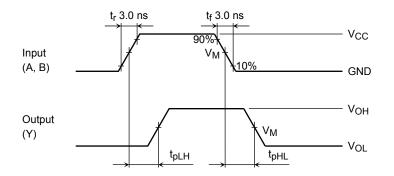
AC Characteristics Measurement Circuit

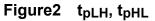


Characteristics	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	V _{CC} x 2
t _{pHZ} , t _{pZH}	GND



AC Characteristics Measurement Circuit





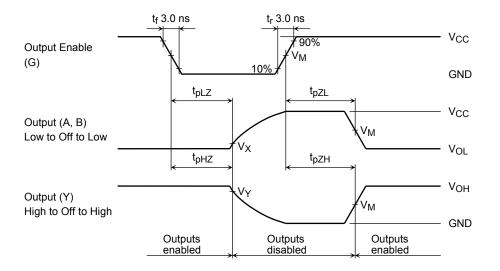
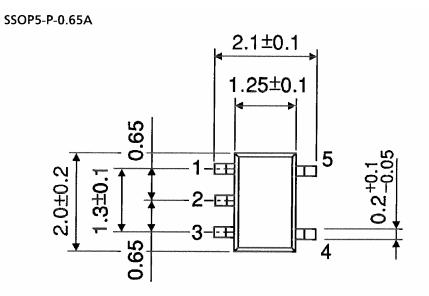


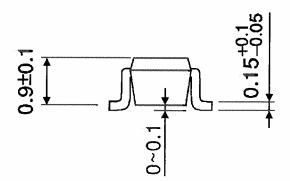
Figure3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

unit	V _{CC}									
anne	3.3±0.3 V	2.5±0.2 V	1.8±0.15 V	1.5±0.1 V	1.2±0.1 V	0.9 V				
VM	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2				
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V				
VY	V _{OH} - 0.3 V	V _{OH} - 0.15 V	V _{OH} - 0.15 V	V _{OH} - 0.1 V	V _{OH} - 0.1 V	V _{OH} - 0.1 V				

TOSHIBA

Package Dimensions





Weight: 0.006 g (typ.)

Unit : mm

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20070701-EN GENERAL

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